Lednium Series Optimal I Flush Mount and Surface Mount Packages



OVTL01LGAx Series

- Robust energy-efficient design with long operating life
- Low thermal resistance (2° C/W)
- Exceptional spatial uniformity
- Available in amber, blue, cyan, green, red, cool white, daylight white, and warm white



The **OVTL01LGAx Series** offers an energy-efficient packaged LED source providing high luminance, low thermal resistance, a water-clear lens, and a long operating lifespan. Devices have a 135° typical viewing angle with optional optics available and two mounting options:

- 1. Flush Mount—The shallow-gullwing package is designed to be countersunk into a hole or cavity in the PC board for a low profile of only 1.12mm.
- 2. Surface Mount—The deep-gullwing package is easily mounted on the solid surface of the PC board (Part numbers end in "S")

Applications

- Automotive exterior and interior lighting
- Architectural lighting
- Electronic signs and signals

Part Number	Viewing Angle	Emitted Color	Typical Luminous Flux (Im)	Package
OVTL01LGAA		Amber	35	Flush Mount
OVTL01LGAB		Blue	12	Flush Mount
OVTL01LGAC		Cyan	40	Flush Mount
OVTL01LGAG		Green	60	Flush Mount
OVTL01LGAR		Red	45	Flush Mount
OVTL01LGAW		Cool White	65	Flush Mount
OVTL01LGAWD		Daylight White	60	Flush Mount
OVTL01LGAWW	1250	Warm White	50	Flush Mount
OVTL01LGAAS	155	Amber	35	Surface Mount
OVTL01LGABS		Blue	12	Surface Mount
OVTL01LGACS		Cyan	40	Surface Mount
OVTL01LGAGS		Green	60	Surface Mount
OVTL01LGARS		Red	45	Surface Mount
OVTL01LGAWS		Cool White	65	Surface Mount
OVTL01LGAWDS		Daylight White	60	Surface Mount
OVTL01LGAWWS		Warm White	50	Surface Mount

DO NOT LOOK DIRECTLY AT LED WITH UNSHIELDED EYES OR DAMAGE TO RETINA MAY OCCUR.



Package Drawing:





Absolute Maximum Ratings

DC Forward Current	0.35 A
Peak Pulsed Forward Current ¹	1 A
Reverse Voltage	5 V
Maximum Allowable Junction Temperature ²	130°C
Storage and Operating Temperature	-50°~+85°C

Notes:

1. Pulse width 1 ms maximum. Duty cycle 1/16.

2. Thermal Resistance junction to Board (T_{jb}) is 2° C/W

Electrical Characteristics (I_F = 350 mA, T_J = 25°C)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS
V _F	Forward Voltage (Amber)	1.9	2.3	2.6	V
	Forward Voltage (Blue)	2.9	3.4	3.7	V
	Forward Voltage (Cyan & Green)	2.9	3.4	3.7	V
	Forward Voltage (Red)	1.9	2.3	2.6	V
	Forward Voltage (White)	2.9	3.4	3.7	V
	V _F —Temperature Co-efficient (Amber & Red)		-6.0		mV/℃
	V _F _Temperature Co-efficient (White & Blue)		-4.8		mV/℃
	V _F —Temperature Co-efficient (Cyan & Green)		-5.0		mV/℃

Optical Characteristics ($I_F = 350 \text{ mA}, T_J = 25 \degree \text{C}$)

COLOR	DOMINANT WAVELENGTH			SPECTRAL FULL-WIDTH		
	MIN	ТҮР	МАХ		TEMPERATORE DEPENDENCE	
Amber	590	595	600	16 nm	0.08 nm/° C	
Blue	455	460	465	24 nm	0.05 nm/° C	
Cyan	500	505	510	37nm	0.04 nm/° C	
Green	510	515	520	40 nm	0.04 nm/° C	
Red	620	625	630	18 nm	0.05 nm/° C	

Color	Minimum CCT (°K)	Maximum CCT (°K)		Chromati	city Coor	dinates	
Cool White	6400	6400 7600 -	C _x	.298	.304	.316	.313
Cool White 640	0400		Cy	.314	.297	.318	.34
Devilientet M/leite	5000	6400	C _x	.313	.317	.336	.338
Daylight White	5200		Cy	.341	.313	.345	.382
Marm Mhite	3200	3800	C _x	.388	.403	.440	.419
vvann vvnite			Cv	.375	.424	.440	.391

OPTEK's Lednium Series Solid State Lighting products package the highest quality LED chips. Typically, the lumen output of these can be as high as 70% after 50,000 hours of operation. This prediction is based on specific test results and on tests on similar materials, and relies on strict observation of the design limits and ratings included in this data sheet.



Standard Bins

Lamps are sorted to luminous flux (Φ) and forward voltage (V_F) bins shown. Orders may be filled with any or all bins contained as below.



Important Notes:

1. All ranks will be included per delivery, rank ratio will be based on the chip distribution.

2. To designate forward voltage and luminous flux ranks, please contact OPTEK.



Standard Bins

Lamps are sorted to luminous flux (Φ) and forward voltage (V_F) bins shown. Orders may be filled with any or all bins contained as below.

OVTL01LGAR and OVTL01LGARS (RED) ($I_F = 350 \text{ mA}$)

Dominant Wavelength 620-630nm



Forward Voltage (V_F)

OVTL01LGAW and OVTL01LGAWS (COOL WHITE) ($I_F = 350 \text{ mA}$)

Typical CCT 7000 ℃ (±600 ℃)

Ê		V3	V4	
ix (Ir	80	C3V3	C3V4	СЗ
ult st	70	C2V3	C2V4	C2
Jinol	60	C1V3	C1V4	C1
Lun	50	2.9 3.	4 3.	.7

Forward Voltage (V_F)

OVTL01LGAWD and OVTL01LGAWDS (DAYLIGHT WHITE) ($I_F = 350 \text{ mA}$)

Typical CCT 5800 ℃ (±600 ℃)



Forward Voltage (V_F)



Standard Bins

Lamps are sorted to luminous flux (Φ) and forward voltage (V_F) bins shown. Orders may be filled with any or all bins contained as below.

OVTL01LGAWW and OVTL01LGAWWS (WARM WHITE) ($I_F = 350 \text{ mA}$)

Typical CCT 3500 °K (±300 °K)



Forward Voltage (V_F)

White Color Bins



	Color	ССТ
W	Cool White	7000 °K ± 600
WD	Daylight White	5800 °K ± 600
ww	Warm White	3500 °K ± 300



CIE Chromaticity Diagram



Spatial Intensity Distribution





Typical Electro-Optical Characteristics Curves





Typical Electro-Optical Characteristics Curves

Luminosity normalized to $T_J = 25^{\circ} C$						
OPTEK Part Number	% Normalized Luminosity at Junction Temperature (°C)					
Number	0	25	50	75	100	125
OVTLO1LGAA(S)	125	100	85	70	60	45
OVTLO1LGAB(S)	107	100	95	87	75	65
OVTLO1LGAG(S)	110	100	95	85	70	65
OVTLO1LGAR(S)	135	100	90	75	65	50
OVTLO1LGAW(S)	105	100	93	82	68	60
OVTLO1LGAWD(S)	105	100	93	82	68	60
OVTLO1LGAWW(S)	105	100	93	82	68	60



Derating Curves - Blue, Green and White LEDs

Luminosity normalized to $T_J = 25 \circ C$ 2.0 1.8 1.6 Normalized Luminosity Red 1.4 Ambe 1.2 Green White 1.0 Blue 0.8 0.6 0.4 0.2 0.0 0 20 40 60 80 100 140 160 120 Junction Temperature °C

Derating of continuous forward current must be observed to prevent maximum junction temperature from being exceeded.



Derating Curves - Amber and Red LEDs

Solder Reflow Cycle



OPTEK Technology Inc. — 1645 Wallace Drive, Carrollton, Texas 75006 Phone: (972) 323-2200 or (800) 341-4747 FAX: (972) 323-2396 visibleLED@optekinc.com www.optekinc.com



Reel Dimensions: Outer diameter: 13 inches [330 mm] Spindle diameter: 0.5 inches [13 mm] Cover tape thickness 0.1.0mm max \odot 0 (°) 0 **Progressive Direction** Empty Pockets Loaded Pockets Empty Pockets Empty Pockets With Tape With Tape With Unsealed (Minimum 50) (Minimum 60) Cover Tape 11 (5-10)

Carrier Tape Dimensions: Loaded quantity 1000 maximum pieces per reel





Thermal Resistance

Optek Lednium Series	<u>1-watt Cup</u> – Measured value 2°C/w	(OVTL01LGAxx)
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Optek Lednium Series 10-watt Matrix – Measured value 2.5°C/w (C

(OVTL09LG3xx)

Theory

In line with industry practice, the thermal resistance (Rth) of our LED packages is stated as $R\theta_{j-b}$, thermal resistance from the junction region (j) of the die, to the board (b) - PCB or other mounting surface. What this means in a practical sense, is that when operating at rated input (1watt approx.) the junction of a die in a cup product will attain a temperature that is 2°C higher than a reference point on the mounting surface beneath it. In the case of a 10-watt Matrix product, the maximum temperature difference between any junction and the reference point is 25°C (2.5°C/w x 10w). The thermal path thus quantified is a composite of a number of thermally resistive elements in a series and or parallel configuration, but lumped together into a single parameter for convenience.

For an end user of LED products then, this constant allows the junction temperature to be determined by a simple measurement of the temperature of the mounting surface. Optek recommends that the design value of sustained die junction temperature be limited to 80° C. In an ambient temperature of 25° C, the board temperature of a 10-watt device must be constrained below 55° C to comply with this recommendation, and for a 1-watt cup the board can theoretically operate at up to 78° C.



From the diagram above it can be seen that the heat generated in the junction region follows a somewhat serial conductive path through the package to the major radiating surface – which in this example is a single sided PCB. Some additional radiation may occur directly from the upper surface of the package (not shown). This would be conducted upward from the die surface through the transparent encapsulating material to the package surface and be radiated from there. To all practical purposes this is a very minor effect. The polymer encapsulants in normal use are poor conductors of heat.



Typical elements in the conducting path and corresponding nominal thermal conductivities are:

	Elements	w/mK
Epilayers	GaN/InGaN	150
Substrate	Sapphire	50
Die attach material	Conductive epoxy	10
Package	Silver plated copper	350
Solder	Solder (Sn/Ag/Cu)	35
Copper cladding	Copper	300

Note : Thermal conductivity is a physical constant. For the materials above, the respective contribution each makes to the overall thermal resistance (R θ_{i-b}) is a function of the thickness of each material layer, and the surface area. Thermal Conductivity (TC) is defined to be the heat conducted in time (t), through thickness (T) in a direction normal to a surface area (A), due to a temperature difference (δT). Therefore

 $TC = q/t \times \{T/[A \times \delta T]\}$

 $\delta T = [Q \times T]/[A \times TC]$ where δT = Temp. difference (K) and Q = Power(w)A = Surface area (m²)T = layer thickness (m)TC = Thermal Conductivity (w/mK)

Theoretical Calculation (for 1 watt dissipated in a cup product via a single 40mil die)

GaN	Thickness approx 10 x 10 ⁻⁶ Area 10 ⁻⁶	= 1 x 10x10 ⁻⁶ / 10 ⁻⁶ x 150 = 0.07 K
Substrate	$T = 60 \times 10^{-6}$	= 1 x 60x10 ⁻⁶ / 10 ⁻⁶ x 50 = 1.2 K
Die attach	$T = 20 \times 10^{-6}$ A = 2 x 10 ⁻⁶	= 1 x 20x10 ⁻⁶ / 2x10 ⁻⁶ x 10 = 1
Package	$T = 0.4 \times 10^{-3} A = 6 \times 10^{-6}$	= 1 x 0.4x10 ⁻³ / 6x10 ⁻⁶ x 350 = 0.19
Solder	$T = 60 \times 10^{-6}$ A = 6x10 ⁻⁶	$= 1 \times 60 \times 10^{-6} / 6 \times 10^{-6} \times 25$ $= 0.4$

Total Calculated $\delta T = 2.86K$



Power input is 1 watt; however, some power is converted into light energy. Assuming this is of the order of 200mw, the adjusted value of δT is 2.29K. The calculation now assumes that all of the dissipation, 800mw of heat, is conducted along the thermal path, thereby ignoring any conduction and subsequent radiation that is not direction-ally normal to the surfaces considered, ie: conduction through the encapsulant material vertically away from the board, and conduction horizontally away from the heat source. The calculation also assumes that there is no contribution to thermal resistance at the boundaries between material layers. In practice it is improbable that perfect transfer will occur at these transition regions, even though the bonding between layers in this example are of high quality. In general, the calculation indicates that the measurements below are of the order of magnitude that can be expected.

The alternate matrix product range is of a much more complicated thermal design, which does not lend itself to a simple theoretical calculation similar to that shown above. There are multiple incident heat sources, parallel heat conduction paths, and significantly larger surface area for stray radiation, eg. Cup above has a surface area available for stray radiation of approximately, 25mm² per watt of input power. A 10-watt matrix product has approximately 92.5mm² of exposed surface per input watt.

Measurements

The key to an accurate measurement of thermal resistance is to obtain a reliable value for the junction temperature (Tj). Since the die itself is, and must be, encapsulated during testing, and the junction is contained within the structure of the die, direct measurement of the junction temperature by normal means is not possible. Two methods of non-contact thermography are available, both of which rely on emitted infrared detection.

Infrared imagery by calibrated radiograph is a possibility; however, in the instance of a cup product only a small value of δT is expected which makes accurate estimation of the actual temperature gradient difficult using colorimetry.

The alternative measurement type is digital infrared thermography. This means there is an inherent uncertainty in the calculation algorithm, which sometimes gives results considered unacceptably inaccurate. In this instance absolute accuracy is of secondary importance because the value to be determined is a temperature difference (δT) which requires only relative values – any error in a first reading will also be present in subsequent readings that are about the same value. The difference between readings is accurate.

The other significant drawback to infrared thermometers is a limitation to minimizing the spot size over which the measurement is made. This poses a difficulty for small assemblies like an LED cup, and in particular the added complication that the calculated temperature is an average value for the area being interrogated further complicates the issue. Another concern is sometimes raised about the ability of this type of instrument to detect a heated surface beyond the closest transparent radiating surface. This is a significant issue for far field measurements; however, it is simple to demonstrate that this does not hold true for the near field, and particularly when the incident beam has a known focal length.



Measurement

Instrument: IR Thermometer Auto ranging: -100 to 1200°C Spot size 3mm D. Focus 25.4mm

Cup Product

Input 350mA at 3.3V(1watt)







Matrix Product

Input 1050mA at 10.2V(10.7watts)





Measurement points



Test set-up on MCPCB